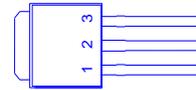
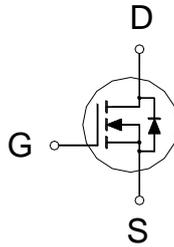




PRODUCT SUMMARY

| | | |
|---------------|---------------|-------|
| $V_{(BR)DSS}$ | $R_{DS(ON)}$ | I_D |
| 500V | 1.55 Ω | 5A |



- 1. GATE
- 2. DRAIN
- 3. SOURCE

100% UIS tested

ABSOLUTE MAXIMUM RATINGS ($T_A = 25\text{ }^\circ\text{C}$ Unless Otherwise Noted)

| PARAMETERS/TEST CONDITIONS | | SYMBOL | LIMITS | UNITS |
|--|-----------------------------------|----------------|------------|------------------|
| Drain-Source Voltage | | V_{DS} | 500 | V |
| Gate-Source Voltage | | V_{GS} | ± 30 | V |
| Continuous Drain Current ² | $T_C = 25\text{ }^\circ\text{C}$ | I_D | 5 | A |
| | $T_C = 100\text{ }^\circ\text{C}$ | | 3.2 | |
| Pulsed Drain Current ^{1, 2} | | I_{DM} | 20 | |
| Avalanche Current ³ | | I_{AS} | 2.5 | |
| Avalanche Energy ³ | | EAS | 31.2 | mJ |
| Power Dissipation | $T_C = 25\text{ }^\circ\text{C}$ | P_D | 62.5 | W |
| | $T_C = 100\text{ }^\circ\text{C}$ | | 25 | |
| Operating Junction & Storage Temperature Range | | T_j, T_{stg} | -55 to 150 | $^\circ\text{C}$ |

THERMAL RESISTANCE RATINGS

| THERMAL RESISTANCE | SYMBOL | TYPICAL | MAXIMUM | UNITS |
|---------------------|-----------------|---------|---------|-----------------------------|
| Junction-to-Case | $R_{\theta JC}$ | | 2 | $^\circ\text{C} / \text{W}$ |
| Junction-to-Ambient | $R_{\theta JA}$ | | 62.5 | |

¹Pulse width limited by maximum junction temperature.

²Limited only by maximum temperature allowed

³ $V_{DD} = 50\text{V}$, $L = 10\text{mH}$, starting $T_J = 25\text{ }^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_J = 25\text{ }^\circ\text{C}$, Unless Otherwise Noted)

| PARAMETER | SYMBOL | TEST CONDITIONS | LIMITS | | | UNIT |
|--------------------------------|---------------|---|--------|-----|-----------|------|
| | | | MIN | TYP | MAX | |
| STATIC | | | | | | |
| Drain-Source Breakdown Voltage | $V_{(BR)DSS}$ | $V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$ | 500 | | | V |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$ | 2 | 3 | 4 | |
| Gate-Body Leakage | I_{GSS} | $V_{DS} = 0\text{V}, V_{GS} = \pm 30\text{V}$ | | | ± 100 | nA |

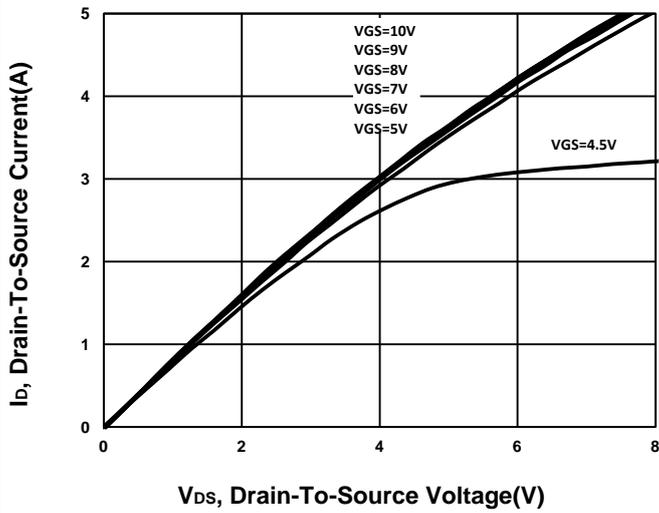
| | | | | | | |
|---|--------------|---|--|------|------|---------------|
| Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 500V, V_{GS} = 0V, T_C = 25\text{ }^\circ\text{C}$ | | | 1 | μA |
| | | $V_{DS} = 400V, V_{GS} = 0V, T_C = 100\text{ }^\circ\text{C}$ | | | 10 | |
| Drain-Source On-State Resistance ¹ | $R_{DS(ON)}$ | $V_{GS} = 10V, I_D = 2.5A$ | | 1.26 | 1.55 | Ω |
| Forward Transconductance ¹ | g_{fs} | $V_{DS} = 10V, I_D = 2.5A$ | | 6.5 | | S |
| DYNAMIC | | | | | | |
| Input Capacitance | C_{iss} | $V_{GS} = 0V, V_{DS} = 25V, f = 1\text{MHz}$ | | 565 | | pF |
| Output Capacitance | C_{oss} | | | 68 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 10 | | |
| Total Gate Charge ² | Q_g | $V_{DD} = 400V, I_D = 5A, V_{GS} = 10V$ | | 18 | | nC |
| Gate-Source Charge ² | Q_{gs} | | | 3 | | |
| Gate-Drain Charge ² | Q_{gd} | | | 7 | | |
| Turn-On Delay Time ² | $t_{d(on)}$ | $V_{DD} = 250V, I_D = 5A, R_G = 6\Omega$ | | 30 | | nS |
| Rise Time ² | t_r | | | 25 | | |
| Turn-Off Delay Time ² | $t_{d(off)}$ | | | 98 | | |
| Fall Time ² | t_f | | | 30 | | |
| SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ($T_J = 25\text{ }^\circ\text{C}$) | | | | | | |
| Continuous Current ³ | I_S | | | | 5 | A |
| Forward Voltage ¹ | V_{SD} | $I_F = 5A, V_{GS} = 0V$ | | | 1 | V |
| Reverse Recovery Time | t_{rr} | $I_F = 5A, di_F/dt = 100A / \mu\text{S}$ | | 277 | | nS |
| Reverse Recovery Charge | Q_{rr} | | | 1.8 | | μC |

¹Pulse test : Pulse Width $\leq 300\text{ }\mu\text{sec}$, Duty Cycle $\leq 2\%$.

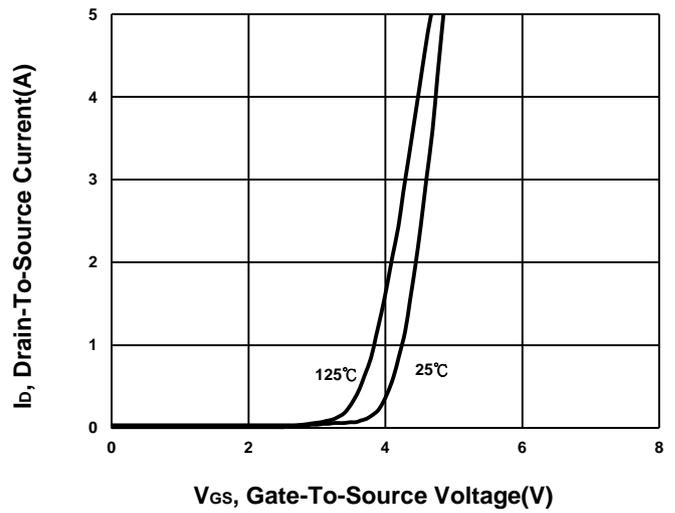
²Independent of operating temperature.

³Pulse width limited by maximum junction temperature.

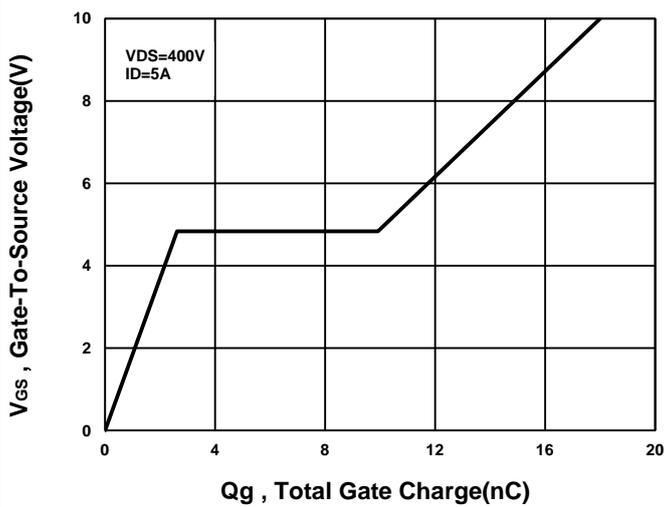
Output Characteristics



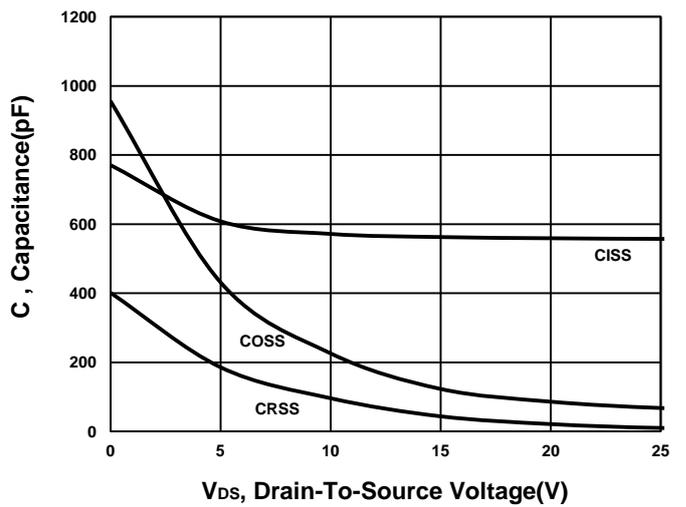
Transfer Characteristics



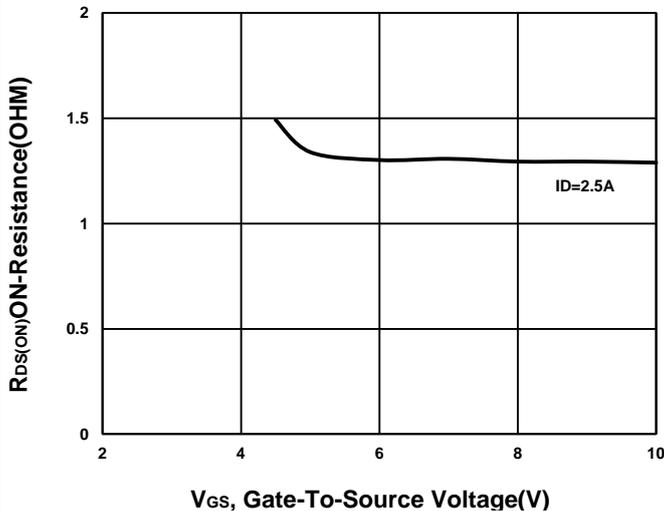
Gate charge Characteristics



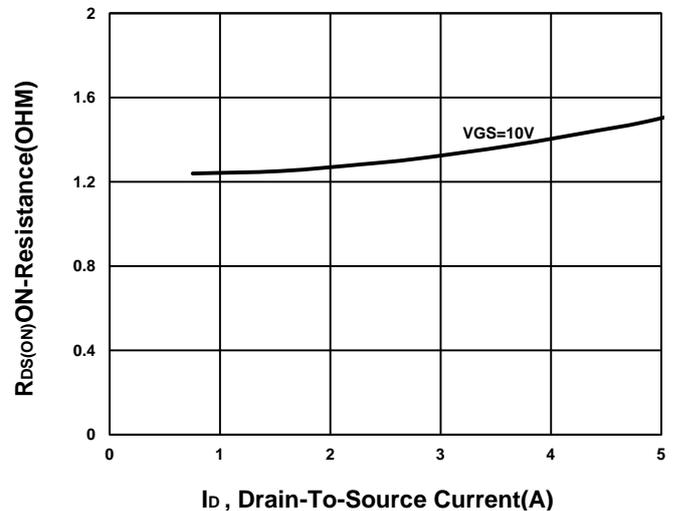
Capacitance Characteristic



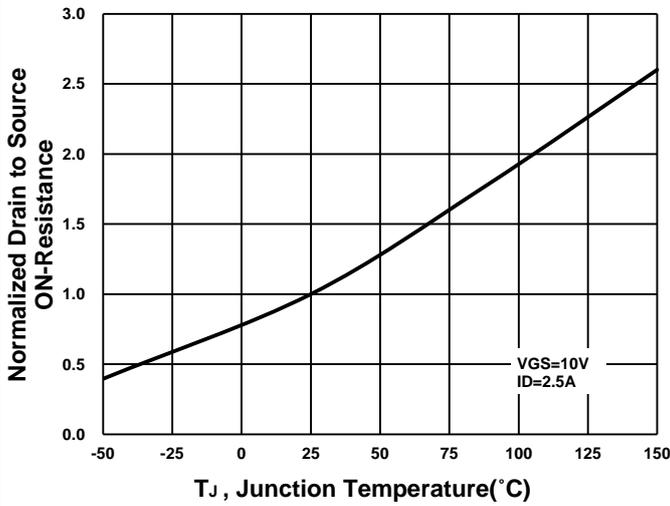
On-Resistance VS Gate-To-Source



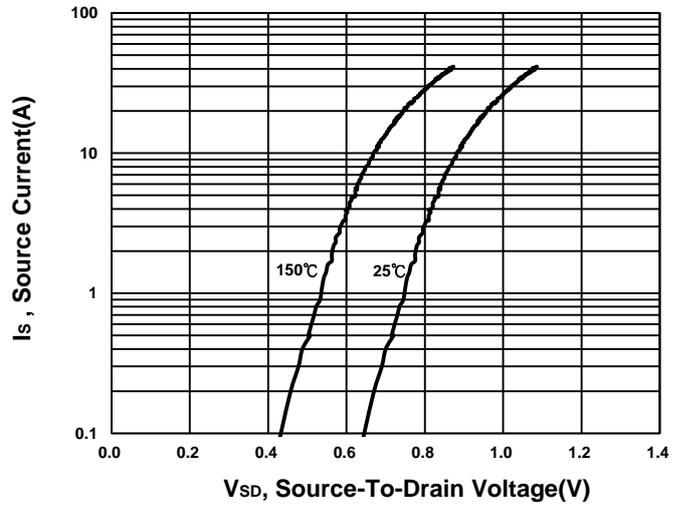
On-Resistance VS Drain Current



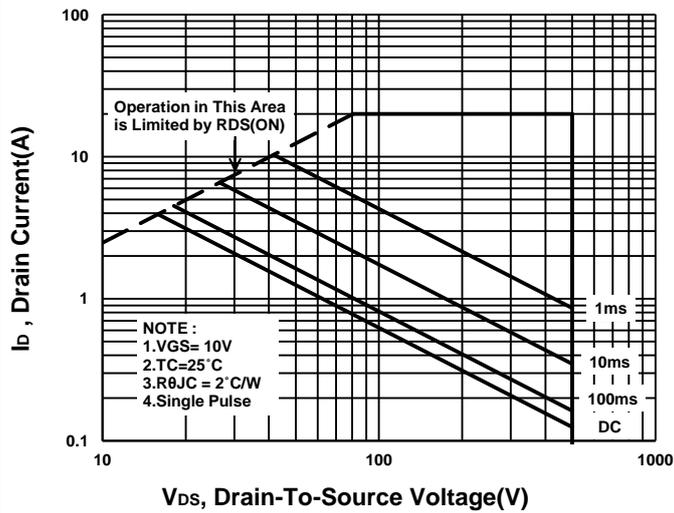
On-Resistance VS Temperature



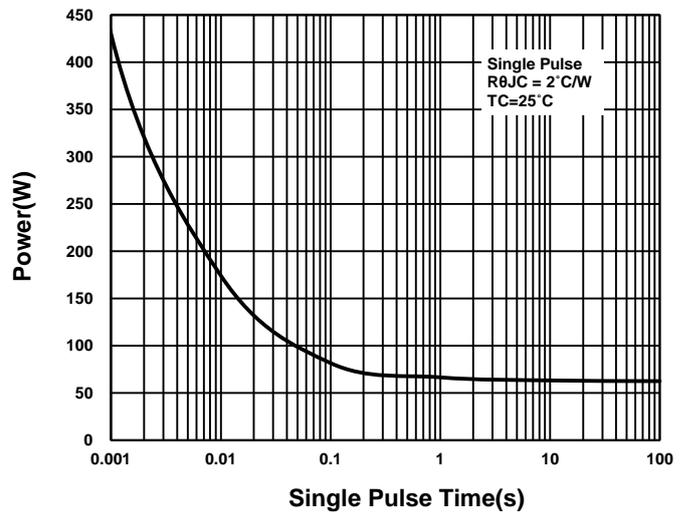
Source-Drain Diode Forward Voltage



Safe Operating Area



Single Pulse Maximum Power Dissipation



Transient Thermal Response Curve

